

How to Place Leakage and Wiring Inductances in the High Frequency Circuit Model

by Lloyd Dixon

TOPIC 7

How to Put Leakage and Wiring Inductances in the High Frequency Circuit Model

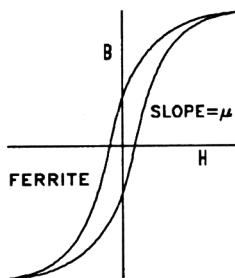
Lloyd H. Dixon, Jr.

OBJECTIVES

1. DEFINE THE ELECTRICAL CIRCUIT EQUIVALENTS OF MAGNETIC DEVICE STRUCTURES TO ENABLE IMPROVED ANALYSIS OF CIRCUIT PERFORMANCE.
2. DEFINE THE MAGNITUDE AND CIRCUIT LOCATION OF RELEVANT PARASITIC MAGNETIC ELEMENTS TO ENABLE PREDICTION OF PERFORMANCE EFFECTS.
3. MANIPULATE PARASITIC ELEMENTS TO OBTAIN IMPROVED OR ENHANCED CIRCUIT PERFORMANCE.
4. ENCOURAGE THE CIRCUIT DESIGNER TO BE MORE INVOLVED WITH MAGNETIC DEVICE DESIGN.

1A

MAGNETIC FUNDAMENTALS



INT'L STD UNITS (S.I.)

RATIONALIZED MKS

UNIT VOLUME PARAMETERS:

B Flux Density

H Field Intens. A-T/m

μ Permeability B/H

ENERGY DENSITY:

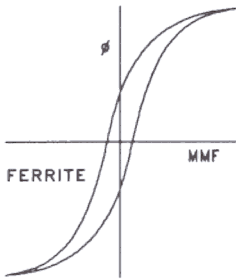
$$W/m^3 = \int H dB \rightarrow BH/2$$

CAN'T FORCE INST. CHANGE

AIR vs. FERRITE

1B

MAGNETIC FUNDAMENTALS



$$\phi = BA \quad \text{Flux} \quad \text{Webers}$$

$$\text{MMF} = Hl \quad \text{Potential} \quad \text{A-T}$$

Slope:

$$P = \phi / \text{MMF} \quad \text{Permeance}$$

AMPERE'S LAW:

$$NI = \int H dl \rightarrow Hl$$

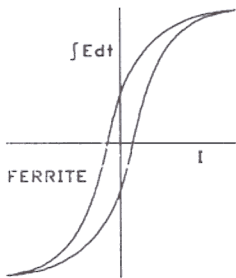
FARADAY'S LAW:

$$d\phi/dt = -E/N; \phi = 1/N \int E dt$$

PERMEANCE IS INDUCTANCE OF 1 TURN

1B1

MAGNETIC FUNDAMENTALS



$$\int E dt = \phi \cdot N \quad (\text{Faraday's Law})$$

$$I = Hl/N \quad (\text{Ampere's Law})$$

$$\text{SLOPE} = L = \int E dt / I$$

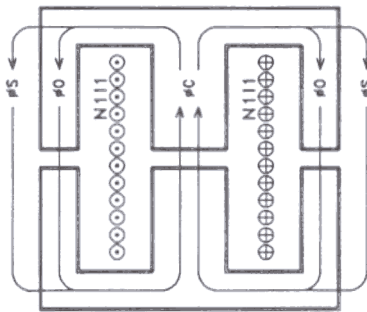
1B2

CONVERSION FACTORS, CGS to SI

		SI	CGS	CGS to SI
FLUX DENSITY	B	Tesla	Gauss	10^{-4}
FIELD INTENSITY	H	A-T/m	Oersted	$1000/4\pi$
PERMEABILITY (space)	μ_0	$4\pi \cdot 10^{-7}$	1	$4\pi \cdot 10^{-7}$
PERMEABILITY (Rel)				1
AREA (Core, Window)	A	m	cm	10^{-4}
LENGTH (Core, Gap)	l	m	cm	10^{-2}
TOTAL FLUX = $\int B dA$	ϕ	Weber	Maxwell	10^{-8}
TOTAL FIELD = $\int H dl$	F, MMF	A-T	Gilbert	$10/4\pi$
RELUCTANCE = MMF/ϕ	R			$10^3/4\pi$
PERMEANCE = $1/R = L/N^2$	P			$4\pi \cdot 10^{-9}$
INDUCTANCE = $P \cdot N^2$	L	Henry	(Henry)	1
ENERGY	W	Joule	Erg	10^{-7}

1C

INDUCTOR — MAGNETIC STRUCTURE

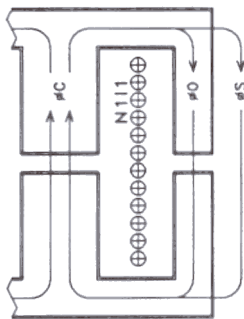


PROBLEMS:
DISTRIBUTED MMF
DISTRIBUTED FLUX
FRINGING FIELD
STRAY FLUX

SIMPLIFY:
COMBINE OUTER LEGS
Symmetry
No Fract. Turns

2

INDUCTOR — MAGNETIC STRUCTURE

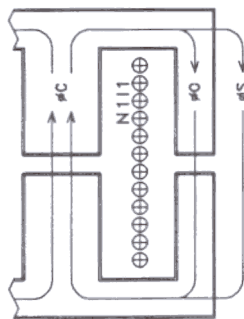


DISTRIBUTED MMF
CIRCULATION

SIMPLIFY:
CONCENTRATE WINDING
IGNORE FRINGING FIELDS
MIN # OF FLUX DIV. POINTS
DEFINE DISCRETE REGIONS

2A

INDUCTOR — MAGNETIC STRUCTURE



ASSUME TYPICAL VALUES:

$$A_e = 1 \text{ cm}^2; \quad \ell_e = 10 \text{ cm}$$

$$A_w = 2 \text{ cm}^2 \quad (\text{ETD34})$$

$$\text{MAX } H\ell = NI_m = J_m A_w = 400 \cdot 2 = 800$$

MAX ENERGY — FULL UTILIZ:

$$W_m = H\ell \cdot B_m A_e / 2$$

$$= 800 \cdot 25 \cdot 0.0001 / 2 = 5 \text{ mJ}$$

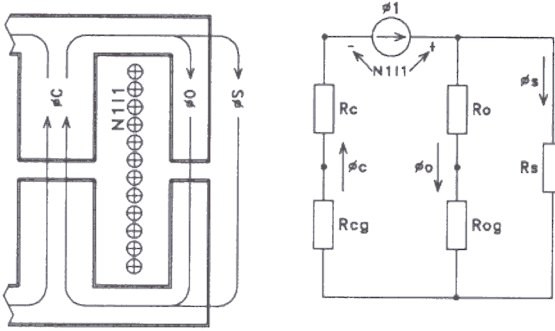
GAP LENGTH — FULL UTILIZ:

$$\ell_g = NI / H = NI \mu / B$$

$$= 800 \cdot 4\pi \cdot 10^{-7} / 0.25 = .4 \text{ cm}$$

2A1

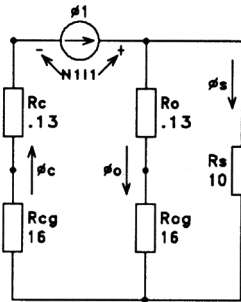
SIMPLIFIED RELUCTANCE MODEL



"DISCRETIZED" - SOURCE, R_c , R_o

2B

SIMPLIFIED RELUCTANCE MODEL



RELUCTANCE = MMF/ϕ

$$R = Hl/BA = l/\mu A$$

APPORTION l_c TO R_c , R_o

APPTN l_g TO R_{cg} , R_{og}

$$\mu = \mu_o \mu_r, \quad \mu_o = 4\pi \cdot 10^{-7}$$

$$\mu_r = 1 \text{ (air)}, = 3000 \text{ (ferrite)}$$

$$R_o = (l_o/2)/(\mu_o \mu_r A_o)$$

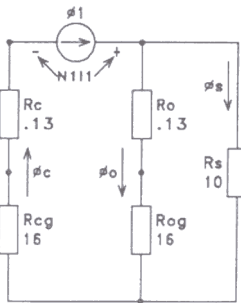
$$= .05/(\mu_o \mu_r \cdot .0001)$$

$$R_o = .133 \cdot 10^3 \text{ (omit } 10^3)$$

R_s IS AN ESTIMATE

2B1

SIMPLIFIED RELUCTANCE MODEL



WITH ALL LEGS GAPPED:

$$R_c \ll R_{cg}; \quad R_o \ll R_{og}$$

STRAY FLUX, $L > \text{PREDICTED}$

WITH OUTERLEG GAP ONLY:

$$R_{cg} = 0; \quad R_c, R_o \ll R_{og}, R_s$$

GREATER STRAY FLUX

WITH CENTERLEG GAP ONLY:

$$R_{og} = 0$$

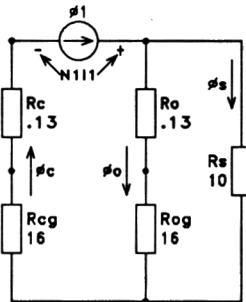
$$R_o \ll R_{cg} \text{ and } R_s$$

MINIMAL STRAY FLUX

R_{cg} TOTALLY DOMINANT

2B2

SIMPLIFIED RELUCTANCE MODEL



CALCULATING:

I1 FROM AMPERE'S LAW

V1 FROM FARADAY'S LAW

IS THIS THE EQUIVALENT
ELECTRICAL CIRCUIT?

PROBLEM:

I1 IS A POTENTIAL

V1 IS A CURRENT

FOUR PROBLEMS

2B3

THE EQUIVALENT ELECTRICAL CIRCUIT

IS A DUAL OF THE MAGNETIC CIRCUIT

(ELECTRICAL DUALS ARE NOT EQUIVALENT: CUK vs FLYBACK)

MAGNETIC - ELECTRICAL DUALITY:

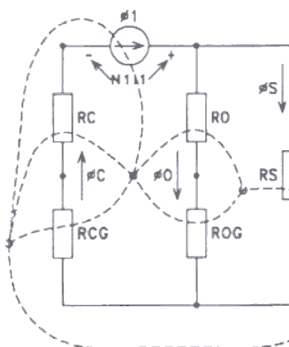
NODES	MESHES (LOOPS)
MMF	AMP-TURNS
$d\phi/dt$	VOLTS/TURN
RELUCTANCE	PERMEANCE
SHORT	OPEN
SERIES ADDN.	PAR. ADDN.

ORIENTATION: ROTATE IN SAME DIRECTION

CIRCUITS MUST BE PLANAR

2C

THE MAGNETIC/ELECTRICAL DUAL



5 NODES ----> 5 LOOPS

3 LOOPS ----> 3 NODES

RELUCTANCE---->PERMEANCE

MMF---->NI

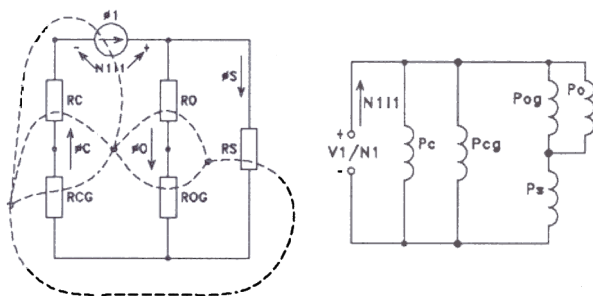
$d\phi/dt$ ---->V/N

ORIENTATION

PLANAR

2C1

THE MAGNETIC/ELECTRICAL DUAL



2C2

THE EQUIVALENT ELECTRICAL CIRCUIT

PERMEANCE = 1/RELUCTANCE

UNITS: Henrys/Turn

$$P = 1/R = \mu A/l = L/N^2$$

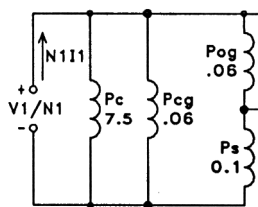
$$P_o = 1/R_o = 7.5 \mu H/N^2$$

$$V_1/N_1 = d\phi/dt$$

$$N_1 I_1 = H l$$

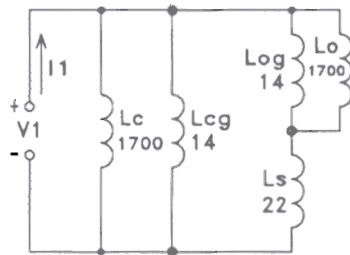
COMBINE INTO ONE

NOTE RELATIVE SIGNIFICANCE



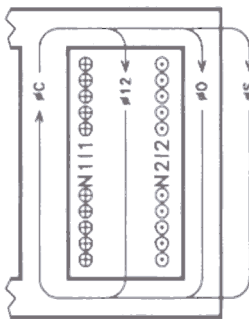
2D

THE EQUIVALENT ELECTRICAL CIRCUIT WITH $N = 15$ TURNS



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SIMPLE TRANSFORMER

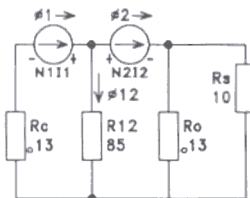


ASSUME V_1 ACROSS N_1
NO LOAD - $I_2 = 0$
MMF IS TINY - NO GAP
 I_1 = MAGNETIZING I_m
 Φ_{12} IS NEGLIGIBLE
WITH FULL LOAD I_2
LARGE MMFs - CANCEL
EXCEPT BETWEEN COILS
 Φ_{12} IS LARGE
LEAKAGE L ENERGY
 $N_1 I_1 = N_2 I_2 + N_1 I_m$

3

TRANSFORMER RELUCTANCE MODEL

ETD34 CORE. R_c , R_o , R_s FROM PREVIOUS EXAMPLE
WINDOW DIM.: BREADTH $b_w = 2.5$ cm, HEIGHT $h_w = .8$ cm
MEAN TURN LENGTH, $MLT = 6$ cm

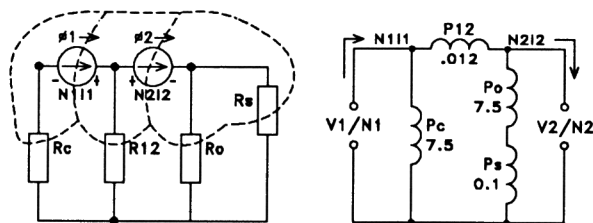


CALCULATE $R_{12} = \frac{l}{\mu A}$
ASSUME WDG CTR = .4 cm
 $A = .4 \cdot 6 = 2.4$ cm
 $= .0024$ m²
 $l = 2.5$ cm = .025 m
 $R_{12} = 85 \cdot 10^6$

ALL R VALUES $\cdot 10^6$

3A

THE TRANSFORMER ELECTRICAL DUAL

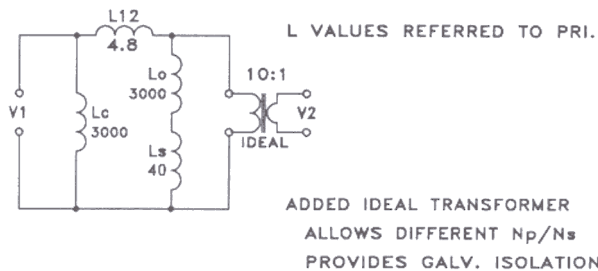


4 LOOPS, 4 NODES IN BOTH

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TRANSFORMER EQUIVALENT CIRCUIT

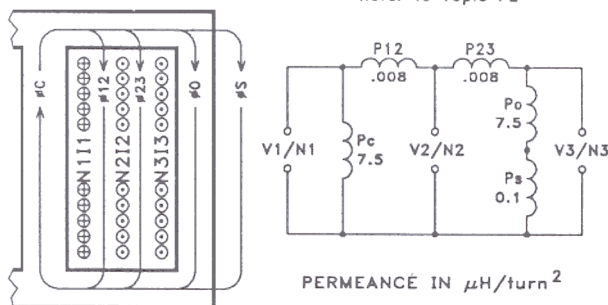
WITH $N_p = 20$ TURNS, $N_s = 2$ TURNS



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THREE-WINDING TRANSFORMER

Refer to Topic P2



4

THREE-WINDING TRANSFORMER

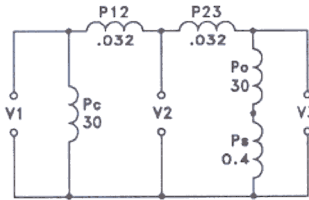
ASSUME $N_p=20$, $N_s=2$

L VALUES IN μH

REF TO 2 TURN SEC.

EXPLORE:

- | | |
|-------------------------------|----------------|
| 1 PRI (N1), 2 SEC (N2,N3) | $T1=10:1$ |
| 1 PRI (N1), 1 SEC (N2 OR N3) | $T1=10:1$ |
| 2 PAR PRI (N1,N2), 1 SEC (N3) | $T1,T2=10:1$ P |
| 2 PAR PRI (N1,N3), 1 SEC (N2) | $T1,T3=10:1$ P |
| 2 SER PRI (N1,N3), 1 SEC (N2) | $T1,T3=5:1$ S |

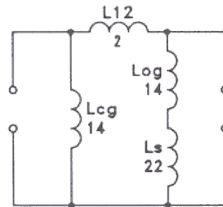
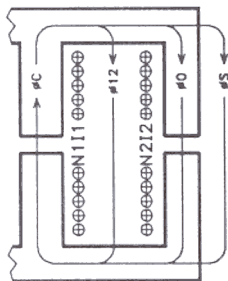


4A

COUPLED INDUCTOR

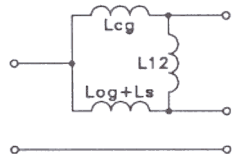
$N1, N2 = 15$ TURNS

L IN μH



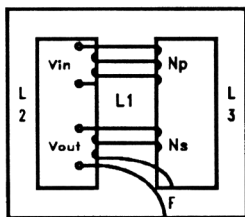
Ref.

Topics
M7. P3



5

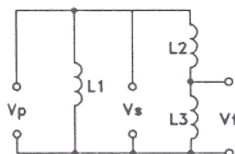
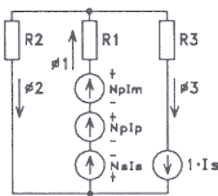
FRACTIONAL TURNS



EFFECTIVE LEAKAGE L

HOW TO STIFFEN UP

Ref. Topic M8



6

REFERENCES

1. CHERRY, E.C., "The Duality Between Electric and Magnetic Circuits and the Formation of Transformer Equivalent Circuits," Proc. Phys. Soc. (Britain), 62B, pp 101-111, Feb. 1949
2. Severns and Bloom, "Modern DC-to-DC Switchmode Power Converter Circuits," Van Nostrand Reinhold Co., Inc., New York, 1985.
3. Dauhalre and Middlebrook, "Modelling and Estimation of Leakage Phenomena in Magnetic Circuits," IEEE Power Electronics Specialists Conference, 1986 Record, pp. 213-226.